S-1142A/B Series

HIGH-WITHSTAND VOLTAGE LOW CURRENT CONSUMPTION LOW DROPOUT CMOS VOLTAGE REGULATOR

© Seiko Instruments Inc., 2009-2014

SII O

Rev.4.2_00

The S-1142A/B Series, developed by using high-withstand voltage CMOS technology, is a positive voltage regulator with a high-withstand voltage, low current consumption, and high-accuracy output voltage.

The S-1142A/B Series operates at a high maximum operating voltage of 50 V and a low current consumption of 4.0 μ A typ. In addition to a built-in low on-resistance transistor which provides a very small dropout voltage and a large output current, this voltage regulator also has a built-in ON / OFF circuit.

An overcurrent protection circuit prevents the load current from exceeding the capacitance of the output transistor, and a built-in thermal shutdown circuit prevents damage caused by heat.

A high heat radiation HSOP-6 package enables high-density mounting.

Features

www.sii-ic.com

Output voltage:	2.0 V to 15.0 V, selectable in 0.1 V step
 Input voltage: 	3.0 V to 50 V
 Output voltage accuracy: 	±1.0% (Tj = +25°C)
	±3.0% (Tj = –40°C to +105°C)
 Current consumption: 	During operation: 4.0 μ A typ., 9.0 μ A max. (Ta = -40°C to +85°C)
	During power-off: 0.1 μ A typ., 1.0 μ A max. (Ta = -40°C to +85°C)
 Output current: 	Possible to output 200 mA ($V_{IN} \ge V_{OUT(S)} + 2.0 \text{ V}$) ^{*1}
 Input and output capacitors: 	A ceramic capacitor of 0.1 μ F or more can be used.
 Built-in overcurrent protection circuit: 	Limits overcurrent of output transistor.
 Built-in thermal shutdown circuit: 	Prevents damage caused by heat.
 Built-in ON / OFF circuit: 	Ensures long battery life.
 Operation temperature range: 	Ta = -40°C to +85°C
 Lead-free (Sn 100%), halogen-free 	

*1. Attention should be paid to the power dissipation of the package when the output current is large.

Application

• Constant-voltage power supply for home electric appliance

Package

• HSOP-6

HIGH-WITHSTAND VOLTAGE LOW CURRENT CONSUMPTION LOW DROPOUT CMOS VOLTAGE REGULATOR S-1142A/B Series Rev.4.2_00

Block Diagram

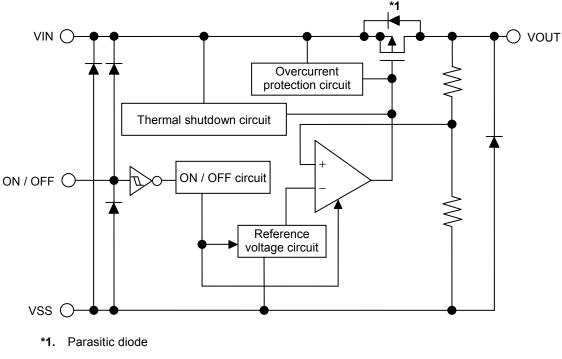
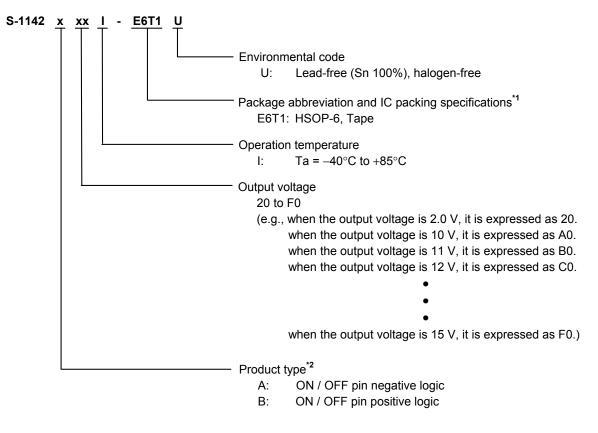


Figure 1

Product Name Structure

Users can select the product type and output voltage for the S-1142A/B Series. Refer to "1. Product name" regarding the contents of product name, "2. Package" regarding the package drawings and "3. Product name list" for details of product names.

1. Product name



- *1. Refer to the tape drawing.
- *2. Refer to "3. ON / OFF pin" in "■ Operation".

Remark When overshoot of the S-1142A/B Series has some influences, consider to use the S-1142C/D Series. Refer to **"6. Overshoot of output voltage"** in **"■ Operation**" regarding details of overshoot.

2. Package

		0		
Package Name	Dimension	Таре	Reel	Land
HSOP-6	FH006-A-P-SD	FH006-A-C-SD	FH006-A-R-SD	FH006-A-L-SD

3. Product name list

Table 2			
Output Voltage	HSOP-6		
2.0 V ± 1.0%	S-1142B20I-E6T1U		
2.5 V ± 1.0%	S-1142B25I-E6T1U		
2.7 V ± 1.0%	S-1142B27I-E6T1U		
2.8 V ± 1.0%	S-1142B28I-E6T1U		
2.85 V ± 1.0%	S-1142B2JI-E6T1U		
$3.0 \text{ V} \pm 1.0\%$	S-1142B30I-E6T1U		
3.2 V ± 1.0%	S-1142B32I-E6T1U		
3.3 V ± 1.0%	S-1142B33I-E6T1U		
3.5 V ± 1.0%	S-1142B35I-E6T1U		
3.7 V ± 1.0%	S-1142B37I-E6T1U		
$4.0~V\pm1.0\%$	S-1142B40I-E6T1U		
$5.0 \text{ V} \pm 1.0\%$	S-1142B50I-E6T1U		
8.0 V ± 1.0%	S-1142B80I-E6T1U		
12.0 V ± 1.0%	S-1142BC0I-E6T1U		
$12.5 \text{ V} \pm 1.0\%$	S-1142BC5I-E6T1U		
15.0 V ± 1.0%	S-1142BF0I-E6T1U		

Remark Please contact our sales office for products with an output voltage other than those listed above or type A products.

Pin Configuration

1. HSOP-6

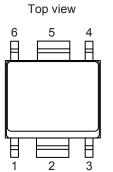


Table 3				
Pin No.	Symbol	Description		
1	VOUT	Output voltage pin		
2	VSS	GND pin		
3	ON / OFF	ON / OFF pin		
4	NC ^{*1}	No connection		
5	VSS	GND pin		
6	VIN	Input voltage pin		

Figure 2

*1. The NC pin is electrically open.

The NC pin can be connected to the VIN pin or the VSS pin.

Absolute Maximum Ratings

		Table 4	
		(Ta = +25°C unless	s otherwise specified)
Item	Symbol	Absolute Maximum Rating	Unit
	V _{IN}	$V_{\rm SS}{-}0.3$ to $V_{\rm SS}{+}60$	V
Input voltage	V _{ON / OFF}	$V_{SS}{-}0.3$ to $V_{IN}{+}0.3$	V
Output voltage	V _{OUT}	$V_{SS} - 0.3$ to $V_{IN} + 0.3$	V
Power dissipation	PD	1900 ^{*1}	mW
Junction temperature	Tj	-40 to +125	۵°
Operation ambient temperature	T _{opr}	-40 to +85	۵°
Storage temperature	T _{stg}	-40 to +125	۵°C

*1. When mounted on board

[Mounted board]

(1) Board size: 50 mm \times 50 mm \times t1.6 mm

(2) Board material: Glass epoxy resin (two layers)

(3) Wiring ratio: 50%

(4) Test conditions: When mounted on board (wind speed: 0 m/s)

(5) Land pattern: Refer to the recommended land pattern (drawing code: FH006-A-L-SD)

Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

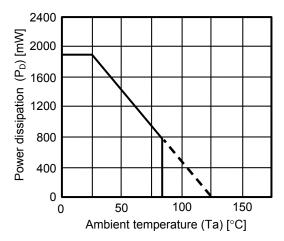


Figure 3 Power Dissipation of Package (When Mounted on Board)

	Table 5	
Condition	Power Dissipation	Thermal Resistance Value (θ j – a)
HSOP-6 (When mounted on board)	1900 mW	53°C/W

Power dissipation of HSOP-6 (reference)

Package power dissipation differs depending on the mounting conditions.

The power dissipation characteristics under the following test conditions should be taken as reference values only.

[Mounted board]

- (1) Board size: 50 mm \times 50 mm \times t1.6 mm
- (2) Board material: Glass epoxy resin (two layers)

(3) Wiring ratio: 90%

- (4) Test conditions: When mounted on board (wind speed: 0 m/s)
- (5) Land pattern: Refer to the recommended land pattern (drawing code: FH006-A-L-SD)

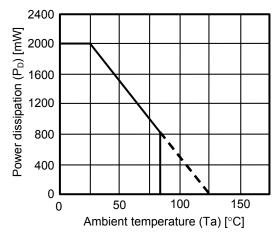


Figure 4 Power Dissipation of Package (When Mounted on Board)

	Table 6	
Condition	Power Dissipation (Reference)	Thermal Resistance Value ($\theta j - a$)
HSOP-6 (When mounted on board)	2000 mW	50°C/W

HIGH-WITHSTAND VOLTAGE LOW CURRENT CONSUMPTION LOW DROPOUT CMOS VOLTAGE REGULATOR Rev.4.2_00 S-1142A/B Series

Item	Symbol		-40° C to $+125^{\circ}$ C, Ta = -40°	Min.	Тур.	Max.	Unit	Test Circui
Output voltage ^{*1}	V _{OUT(E)}	$V_{IN} = V_{OUT(S)} + 1.0 V,$ $I_{OUT} = 30 mA, -40^{\circ}C$	$V_{OUT(S)} \times 0.97$	V _{OUT(S)}	$V_{OUT(S)} \times 1.03$	V	1	
Output current*2	I _{OUT}	$V_{IN} \ge V_{OUT(S)} + 2.0 V$,	200*4	_	_	mA	3
	.001		$2.0 \text{ V} \le \text{V}_{\text{OUT}(S)} \le 2.2 \text{ V}$		1.0	_	V	1
			$2.2 V \le V_{OUT(S)} < 2.4 V$	_	0.8	_	v	1
			$2.4 \text{ V} \le \text{V}_{\text{OUT}(S)} < 2.6 \text{ V}$	_	0.6	_	V	1
			$2.6 \text{ V} \le \text{V}_{\text{OUT}(S)} < 3.0 \text{ V}$	_	0.45	_	v	1
		I _{OUT} = 100 mA	$3.0 \text{ V} \le \text{V}_{\text{OUT}(S)} < 3.5 \text{ V}$	_	0.35	_	V	1
		$Ta = +25^{\circ}C$	$3.5 V \le V_{OUT(S)} < 4.0 V$	_	0.3	_	V	1
			$4.0 V \le V_{OUT(S)} < 5.0 V$	_	0.27	_	V	1
			$5.0 \text{ V} \le \text{V}_{\text{OUT}(S)} < 7.0 \text{ V}$	_	0.23	_	V	1
			$7.0 V \le V_{OUT(S)} < 9.0 V$	_	0.2	_	v	1
*2			$9.0 V \le V_{OUT(S)} \le 15.0 V$	_	0.18	_	V	1
Dropout voltage ^{*3}	V _{drop}		$2.0 V \le V_{OUT(S)} < 2.2 V$	_	1.12	_	V	1
			$2.2 V \le V_{OUT(S)} < 2.4 V$	_	1.02	_	v	1
			$2.4 \text{ V} \le \text{V}_{\text{OUT(S)}} < 2.6 \text{ V}$	_	0.92	_	v	1
			$2.6 \text{ V} \le \text{V}_{\text{OUT}(S)} < 3.0 \text{ V}$	_	0.82	_	v	1
		I _{OUT} = 200 mA	$3.0 \text{ V} \le \text{V}_{\text{OUT}(S)} < 3.5 \text{ V}$	_	0.72	_	v	1
		Ta = +25°C	$3.5 \text{ V} \le \text{V}_{\text{OUT}(S)} < 4.0 \text{ V}$	_	0.62	_	v	1
		10 120 0	$4.0 V \le V_{OUT(S)} < 5.0 V$	_	0.55	_	V	1
			$5.0 V \le V_{OUT(S)} < 7.0 V$	_	0.5	_	V	1
			$7.0 \text{ V} \le \text{V}_{OUT(S)} < 9.0 \text{ V}$	_	0.45	_	V	1
			$9.0 V \le V_{OUT(S)} \le 15.0 V$	_	0.40	_	V	1
Line regulation	$\frac{\Delta V_{OUT1}}{\Delta V_{IN} \bullet V_{OUT}}$	$V_{OUT(S)}$ + 1.0 V \leq V _{IN} \leq	_	0.05	0.3	%/V	1	
		$\begin{split} & V_{IN} = V_{OUT(S)} + 1.0 \; V, \; 2.0 \; V \leq V_{OUT(S)} < 5.1 \; V, \\ & 0.1 \; mA \leq I_{OUT} \leq 40 \; mA \\ & V_{IN} = V_{OUT(S)} + 1.0 \; V, \; 5.1 \; V \leq V_{OUT(S)} < 12.1 \; V, \\ & 0.1 \; mA \leq I_{OUT} \leq 40 \; mA \\ & V_{IN} = V_{OUT(S)} + 1.0 \; V, \; 12.1 \; V \leq V_{OUT(S)} \leq 15.0 \; V, \\ & 0.1 \; mA \leq I_{OUT} \leq 40 \; mA \end{split}$		_	20	40	mV	1
Load regulation	ΔV_{OUT2}			_	20	60	mV	1
				-	20	80	mV	1
Current consumption during operation	ISS1	$V_{IN} = V_{OUT(S)} + 1.0 V,$ ON / OFF pin = ON, r	no load	_	4.0	9.0	μA	2
Current consumption during power-off	1552	$V_{IN} = V_{OUT(S)} + 1.0 V$, ON / OFF pin = OFF, no load		-	0.1	1.0	μA	2
Input voltage	V _{IN}		_	3.0	-	50	V	-
ON / OFF pin input voltage "H"	V _{SH}	$V_{IN} = V_{OUT(S)} + 1.0 V,$ determined by V_{OUT} c	output level	1.5	_	_	V	4
ON / OFF pin input voltage "L"	V _{SL}	$V_{IN} = V_{OUT(S)} + 1.0 V,$ determined by V_{OUT} of		-	_	0.3	V	4
ON / OFF pin input current "H"	I _{SH}	$V_{IN} = V_{OUT(S)} + 1.0 \text{ V}, V_{ON / OFF} = V_{OUT(S)} + 1.0 \text{ V}$		-0.1	-	0.1	μA	4
ON / OFF pin input current "L"	I _{SL}	$V_{IN} = V_{OUT(S)} + 1.0 \text{ V}, V_{ON/OFF} = 0 \text{ V}$		-0.1	-	0.1	μA	4
			$2.0 V \le V_{OUT(S)} \le 2.3 V$	-	50	-	dB	5
Dinnla raiastias		f = 100 Hz,	$2.3 V \le V_{OUT(S)} < 3.6 V$	-	45	-	dB	5
Ripple rejection	RR	$\Delta V_{rip} = 0.5 Vrms,$ I _{OUT} = 30 mA,	$3.6 V \le V_{OUT(S)} < 6.1 V$	-	40	-	dB	5
		$T_{OUT} = 30 \text{ mA},$ Ta = +25°C	$6.1 \text{ V} \le \text{V}_{\text{OUT}(S)} < 10.1 \text{ V}$	-	35	-	dB	5
Short-circuit current	I _{short}	$V_{IN} = V_{OUT(S)} + 1.0 V,$		_	30 80	_	dB mA	5 3
Thermal shutdown detection temperature	T _{SD}	$V_{OUT} = 0 V$, Ta = +25 Junction temperature		_	150	_	°C	_
Thermal shutdown release temperature	T _{SR}	Junction temperature	_	125	_	°C	_	

Electrical Characteristics

***1.** V_{OUT(S)}: Set output voltage

V_{OUT(E)}: Actual output voltage

The output voltage when fixing I_{OUT} (= 30 mA) and inputting $V_{OUT(S)}$ + 1.0 V

*2. The output current at which the output voltage becomes 95% of V_{OUT(E)} after gradually increasing the output current.

***3.** $V_{drop} = V_{IN1} - (V_{OUT3} \times 0.98)$

 V_{OUT3} is the output voltage when V_{IN} = $V_{OUT(S)}$ + 2.0 V, and I_{OUT} = 100 mA or 200 mA.

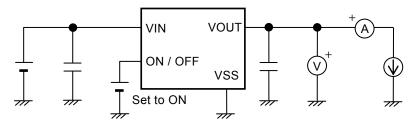
 V_{IN1} is the input voltage at which the output voltage becomes 98% of V_{OUT3} after gradually decreasing the input voltage.

*4. The output current can be at least this value.

Due to limitation of the package power dissipation, this value may not be satisfied. Attention should be paid to the power dissipation of the package when the output current is large. This specification is guaranteed by design.

HIGH-WITHSTAND VOLTAGE LOW CURRENT CONSUMPTION LOW DROPOUT CMOS VOLTAGE REGULATOR S-1142A/B Series Rev.4.2_00

Test Circuits





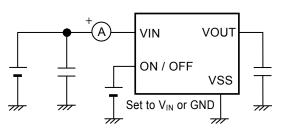
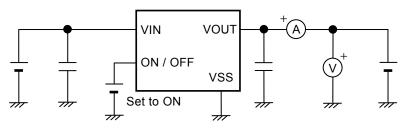
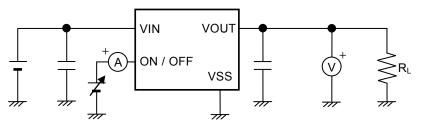
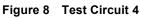


Figure 6 Test Circuit 2









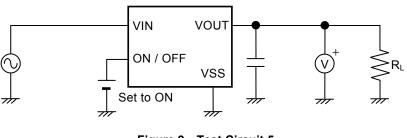
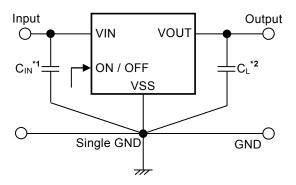


Figure 9 Test Circuit 5

Standard Circuit



*1. C_{IN} is a capacitor for stabilizing the input. *2. A ceramic capacitor of 0.1 μ F or more can be used as C_L .

Figure 10

Caution The above connection diagram and constants will not guarantee successful operation. Perform thorough evaluation using an actual application to set the constants.

Condition of Application

Input capacitor (C_{IN}): 0.1 μ F or more Output capacitor (C_L): 0.1 μ F or more

■ Selection of Input and Output Capacitors (C_{IN}, C_L)

The S-1142A/B Series requires an output capacitor between the VOUT pin and the VSS pin for phase compensation. Operation is stabilized by a ceramic capacitor with an output capacitance of 0.1 μ F or more over the entire temperature range. When using an OS capacitor, a tantalum capacitor, or an aluminum electrolytic capacitor, the capacitance must be 0.1 μ F or more.

The values of output overshoot and undershoot, which are transient response characteristics, vary depending on the value of the output capacitor.

The required value of capacitance for the input capacitor differs depending on the application.

Set the value for input capacitor (C_{IN}) and output capacitor (C_L) as follows.

 $\begin{array}{l} C_{\text{IN}} \geq 0.1 \; \mu F \\ C_{\text{L}} \geq 0.1 \; \mu F \end{array} \label{eq:cinetic}$

Caution Define the capacity values of C_{IN} and C_L by sufficient evaluation including the temperature characteristics under the actual usage conditions.

Caution Generally a series regulator may cause oscillation, depending on the selection of external parts. Confirm that no oscillation occurs in the application for which the above capacitors are used.

Explanation of Terms

1. Low dropout voltage regulator

This voltage regulator has the low dropout voltage due to its built-in low on-resistance transistor.

2. Output voltage (VOUT)

The accuracy of the output voltage is ensured at $\pm 3.0\%$ under specified conditions of fixed input voltage^{*1}, fixed output current, and fixed temperature.

*1. Differs depending on the product.

Caution If the above conditions change, the output voltage value may vary and exceed the accuracy range of the output voltage. Refer to "■ Electrical Characteristics" and "■ Characteristics (Typical Data)" for details.

3. Line regulation
$$\left(\frac{\Delta V_{OUT1}}{\Delta V_{IN} \bullet V_{OUT}}\right)$$

Indicates the dependency of the output voltage against the input voltage. That is, the value shows how much the output voltage changes due to a change in the input voltage after fixing output current constant.

4. Load regulation (ΔV_{OUT2})

Indicates the dependency of the output voltage against the output current. That is, the value shows how much the output voltage changes due to a change in the output current after fixing input voltage constant.

5. Dropout voltage (V_{drop})

Indicates the difference between input voltage (V_{IN1}) and the output voltage when; decreasing input voltage (V_{IN}) gradually until the output voltage has dropped out to the value of 98% of output voltage (V_{OUT3}), which is at V_{IN} = $V_{OUT(S)} + 2.0 V$.

 $V_{drop} = V_{IN1} - (V_{OUT3} \times 0.98)$

Operation

1. Basic operation

Figure 11 shows the block diagram of the S-1142A/B Series.

The error amplifier compares the reference voltage (V_{ref}) with feedback voltage (V_{fb}), which is the output voltage resistance-divided by feedback resistors (R_s and R_f). It supplies the gate voltage necessary to maintain the constant output voltage which is not influenced by the input voltage and temperature change, to the output transistor.

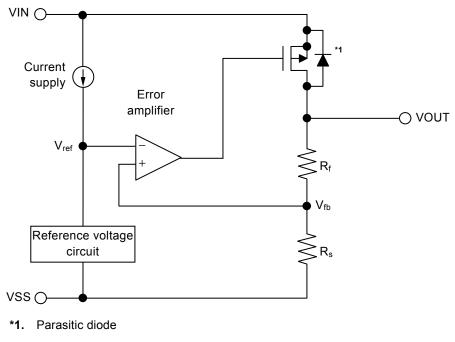


Figure 11

2. Output transistor

In the S-1142A/B Series, a low on-resistance P-channel MOS FET is used as the output transistor.

Be sure that V_{OUT} does not exceed V_{IN} + 0.3 V to prevent the voltage regulator from being damaged due to reverse current flowing from the VOUT pin through a parasitic diode to the VIN pin, when the potential of V_{OUT} became higher than V_{IN}.

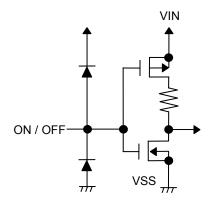
3. ON / OFF pin

This pin starts and stops the regulator.

When the ON / OFF pin is set to the OFF level, the entire internal circuit stops operating, and the built-in P-channel MOS FET output transistor between the VIN pin and the VOUT pin is turned off, reducing current consumption significantly. The VOUT pin is set to the V_{SS} level by the internal dividing resistor of several M Ω between the VOUT pin and the VSS pin.

Note that the current consumption increases when a voltage of 0.3 V to V_{IN} – 0.3 V is applied to the ON / OFF pin. The ON / OFF pin is configured as shown in **Figure 12**. Since the ON / OFF pin is neither pulled down nor pulled up internally, do not use it in the floating status. When not using the ON / OFF pin, connect it to the VSS pin in the product A type, and connect it to the VIN pin in the B type.

Table 8						
Product Type	ON / OFF Pin	Internal Circuit	VOUT Pin Voltage	Current Consumption		
А	"L": ON	Operate	Set value	I _{SS1}		
А	"H": OFF	Stop	V _{SS} level	I _{SS2}		
В	"L": OFF	Stop	V _{SS} level	I _{SS2}		
В	"H": ON	Operate	Set value	I _{SS1}		





4. Overcurrent protection circuit

The S-1142A/B Series includes an overcurrent protection circuit which having the characteristics shown in "1. Output voltage vs. Output current (When load current increases) ($Ta = +25^{\circ}C$)" in "
Characteristics (Typical Data)", in order to protect the output transistor against an excessive output current and short circuiting between the VOUT pin and the VSS pin. The current when the output pin is short-circuited (I_{short}) is internally set at approx. 80 mA typ., and the normal value is restored for the output voltage, if releasing a short circuit once.

Caution This overcurrent protection circuit does not work as for thermal protection. If this IC long keeps short circuiting inside, pay attention to the conditions of input voltage and load current so that, under the usage conditions including short circuit, the loss of the IC will not exceed power dissipation of the package.

5. Thermal shutdown circuit

The S-1142A/B Series has a thermal shutdown circuit to protect the device from damage due to overheat. When the junction temperature rises to 150°C typ., the thermal shutdown circuit operates to stop regulating. When the junction temperature drops to 125°C typ., the thermal shutdown circuit is released to restart regulating. Due to self-heating of the S-1142A/B Series, if the thermal shutdown circuit starts operating, it stops regulating so

that the output voltage drops. When regulation stops, the S-1142A/B Series does not itself generate heat and the IC's temperature drops. When the temperature drops, the thermal shutdown circuit is released to restart regulating, thus this IC generates heat again. Repeating this procedure makes the waveform of the output voltage into a pulse-like form. Stop or restart of regulation continues unless decreasing either or both of the input voltage and the output current in order to reduce the internal power consumption, or decreasing the ambient temperature.

Table 9		
Thermal Shutdown Circuit	VOUT Pin Voltage	
Operate: 150°C typ.*1	V _{SS} level	
Release: 125°C typ.*1	Set value	

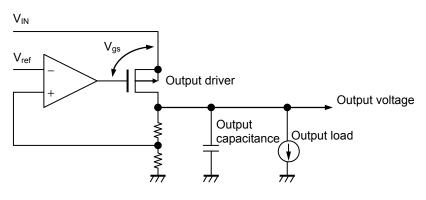
***1.** Junction temperature

6. Overshoot of output voltage

Overshoot of output voltage occurs depending on the condition such as the rising speed of input voltage (V_{IN}). Overshoot voltage is the difference between the maximum value of output voltage generated by the fluctuation of V_{IN} and the actual output voltage ($V_{OUT(E)}$) value.

6.1 At normal operation

As shown in **Figure 13**, V_{gs} is the voltage difference between V_{IN} and gate voltage of output driver. The error amplifier controls V_{gs} in order to keep the output voltage constant depending on the fluctuation of V_{IN} and the output load.





6. 2 Occurrence of overshoot

If V_{IN} voltage rises at a fast speed, V_{gs} may become large when gate voltage of output driver can not follow the speed of V_{IN} . When V_{gs} becomes large, the current supplied from output driver is increased transiently. Thereby, output voltage rises, and then overshoot occurs.

Note that overshoot voltage is greatly affected by the following use conditions or temperature, etc.

- When V_{IN} rises in the range of 2.0 V to $V_{OUT(E)}$.
- \bullet When the rising speed of V_{IN} is fast.
- When the output capacitance is small.
- When the output load is small.

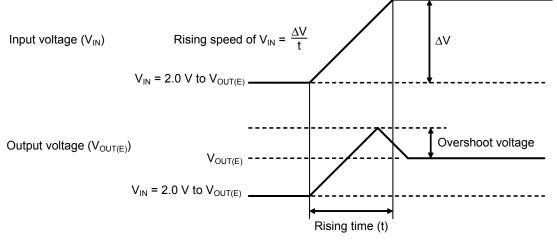


Figure 14 V_{IN} and Overshoot Voltage

Caution Under the following conditions, overshoot voltage tends to become larger especially. • When V_{IN} rises from around 98% of V_{OUT(E)}.

• When the rising speed of V_{IN} is 10 mV/µs or more.

Remark When overshoot of the S-1142A/B Series has some influences, consider to use the S-1142C/D Series.

Precautions

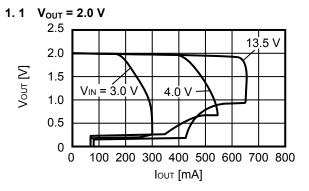
- Wiring patterns for the VIN pin, the VOUT pin and GND should be designed so that the impedance is low. When mounting an output capacitor between the VOUT pin and the VSS pin (C_L) and a capacitor for stabilizing the input between the VIN pin and the VSS pin (C_{IN}), the distance from the capacitors to these pins should be as short as possible.
- Note that generally the output voltage may increase when a series regulator is used at low load current (0.1 mA or less).
- Note that generally the output voltage may increase due to the leakage current from an output driver when a series regulator is used at high temperature.
- Note that the output voltage may increase due to the leakage current from an output driver even if the ON / OFF pin is at OFF level when a series regulator is used at high temperature.
- Generally a series regulator may cause oscillation, depending on the selection of external parts. The following conditions are recommended for the S-1142A/B Series. However, be sure to perform sufficient evaluation under the actual usage conditions for selection, including evaluation of temperature characteristics. Refer to "6. Example of equivalent series resistance vs. Output current characteristics (Ta = +25°C)" in "■ Reference Data" for the equivalent series resistance (R_{ESR}) of the output capacitor.

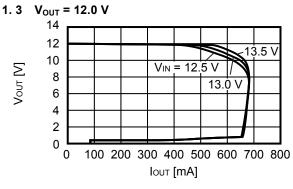
Input capacitor (C _{IN}):	0.1 μF or more
Output capacitor (C _L):	0.1 µF or more

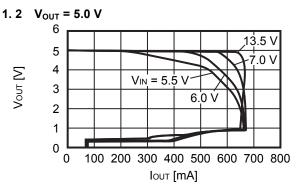
- The voltage regulator may oscillate when the impedance of the power supply is high and the input capacitance is small or an input capacitor is not connected.
- Sufficiently evaluate the output voltage fluctuations caused by the power supply or the load fluctuations with the actual device.
- Overshoot may occur in the output voltage momentarily if the voltage is rapidly raised at power-on or when the power supply fluctuates. Sufficiently evaluate the output voltage at power-on with the actual device.
- The application conditions for the input voltage, the output voltage, and the load current should not exceed the package power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- In determining the output current, attention should be paid to the output current value specified in Table 7 in "
 Electrical Characteristics" and footnote *4 of the table.
- SII claims no responsibility for any disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

Characteristics (Typical Data)

1. Output voltage vs. Output current (When load current increases) (Ta = +25°C)



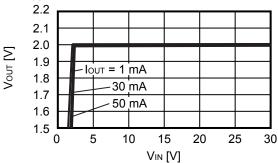




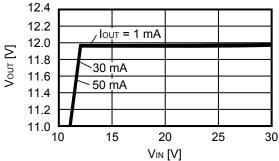
- **Remark** In determining the output current, attention should be paid to the following.
 - The minimum output current value and footnote *4 of Table 7 in the "■ Electrical Characteristics"
 - 2. Power dissipation of the package

2. Output voltage vs. Input voltage (Ta = +25°C)

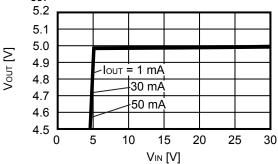
2.1 V_{OUT} = 2.0 V



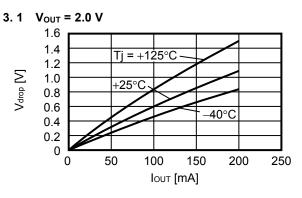
2. 3 V_{OUT} = 12.0 V

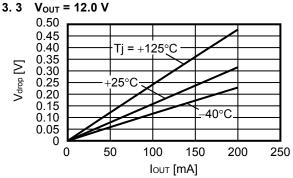


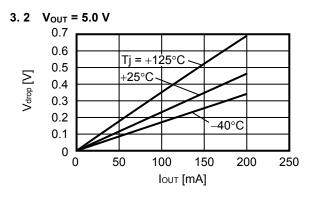
2. 2 V_{OUT} = 5.0 V

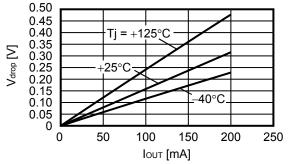


3. Dropout voltage vs. Output current



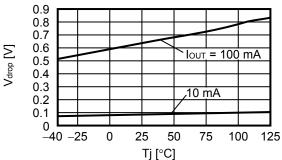


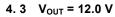


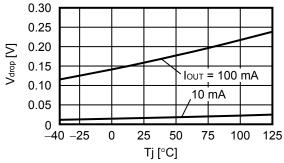


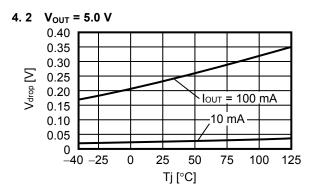
4. Dropout voltage vs. Temperature



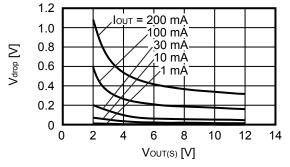




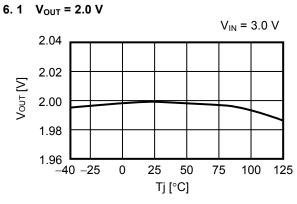




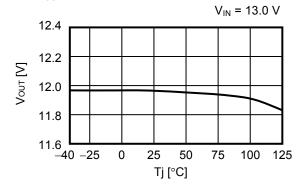
5. Dropout voltage vs. Set output voltage (Tj = +25°C)



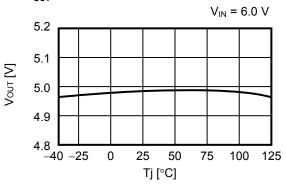
6. Output voltage vs. Temperature



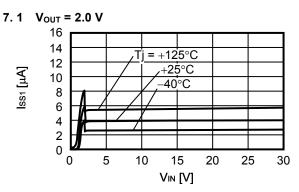
6.3 V_{OUT} = 12.0 V

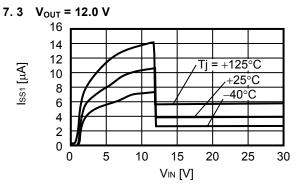


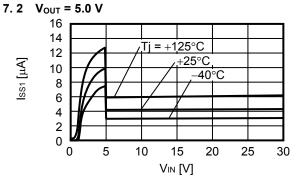
6. 2 V_{OUT} = 5.0 V



7. Current consumption during operation vs. Input voltage (When ON / OFF pin is ON, no load)

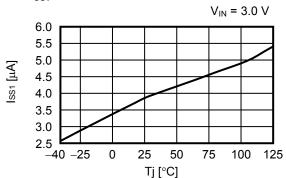


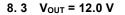


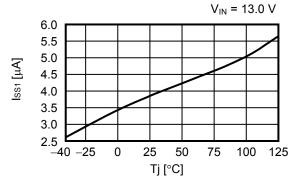


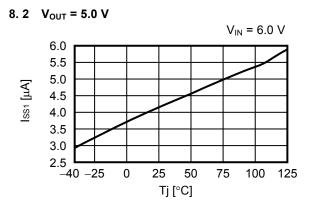
8. Current consumption during operation vs. Temperature

8.1 V_{OUT} = 2.0 V



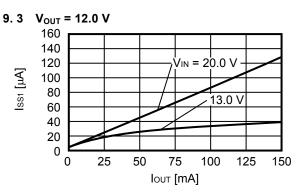


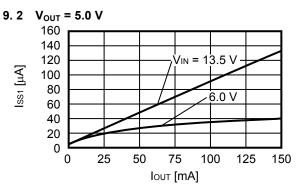




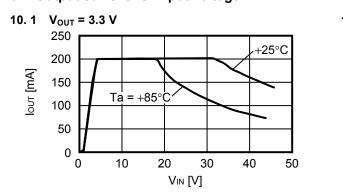
9.1 V_{OUT} = 2.0 V 160 140 120 /ın = 13.5 V [hA] 100 80 SS1 3.0 V 60 40 20 0 0 25 50 75 100 125 150 IOUT [mA]

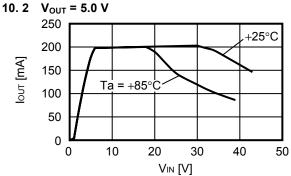






10. Output current vs. Input voltage^{*1}





*1. When mounted on board

[Mounted board]

- (1) Board size:

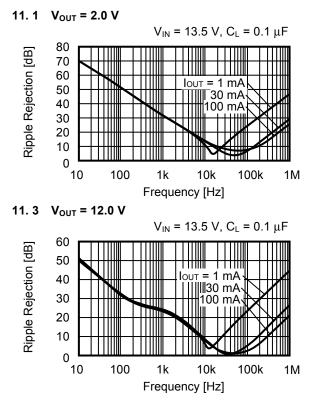
```
(2) Board material: Glass epoxy resin (two layers)
```

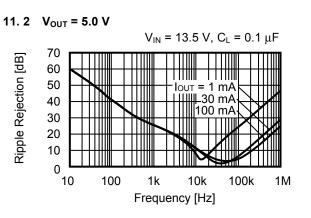
(3) Wiring ratio: Surface approx. 75%, reverse side approx. 90%

50 mm \times 50 mm \times t1.6 mm

(4) Through hole: Diameter 0.5 mm × 24

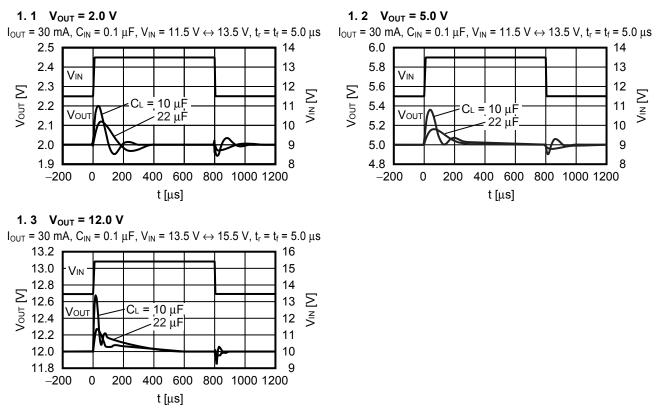
11. Ripple rejection (Ta = +25°C)





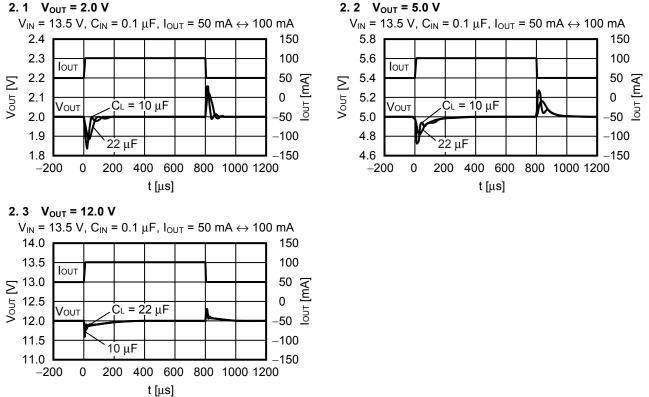
Reference Data

1. Characteristics of input transient response (Ta = +25°C)



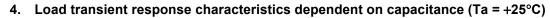
2. Characteristics of load transient response (Ta = +25°C)

2.1 V_{OUT} = 2.0 V

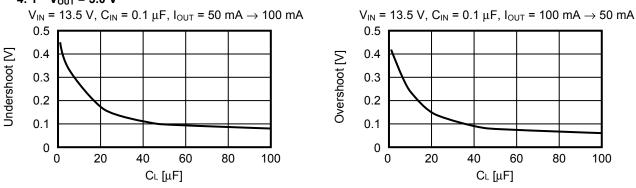


3.1 V_{OUT} = 3.3 V 3.2 V_{OUT} = 5.0 V V_{IN} = 13.5 V, C_{L} = 10 $\mu\text{F},\,C_{\text{IN}}$ = 0.1 $\mu\text{F},$ V_{IN} = 13.5 V, C_L = 10 μ F, C_{IN} = 0.1 μ F, I_{OUT} = 100 mA, $V_{ON\,/\,OFF}$ = 0 V \rightarrow 13.5 V I_{OUT} = 100 mA, $V_{ON\,/\,OFF}$ = 0 V \rightarrow 13.5 V 18 15 18 15 12 12 12 12 6 Σ 6 ∑ 9 9 Vout [V] Von/off Vour [V] Von/off Von/off Von/off 6 6 0 3 3 -6 Vout Vout -12 0 0 -12 -18 -18 -3 -3 -500 0 500 1000 1500 2000 -5000 500 1000 1500 2000 t [µs] t [µs]

3. Transient response characteristics of ON / OFF pin (Ta = +25°C)

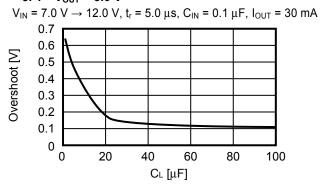






5. Input transient response characteristics dependent on capacitance (Ta = +25°C)

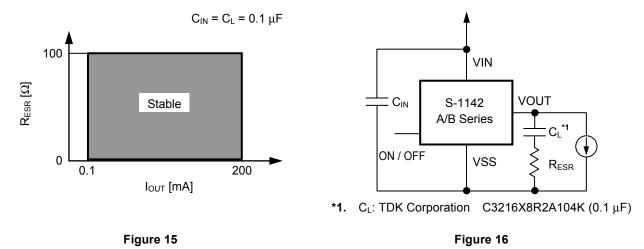
5. 1 V_{OUT} = 5.0 V



 V_{IN} = 12.0 V \rightarrow 7.0 V, t_{r} = 5.0 $\mu s,\,C_{\text{IN}}$ = 0.1 $\mu F,\,I_{\text{OUT}}$ = 30 mA 0.7 0.6 Undershoot [V] 0.5 0.4 0.3 0.2 0.1 0 0 20 40 60 80 100

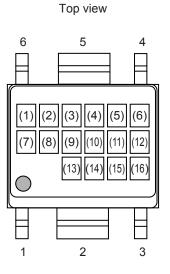
C∟ [µF]

6. Example of equivalent series resistance vs. Output current characteristics (Ta = +25°C)

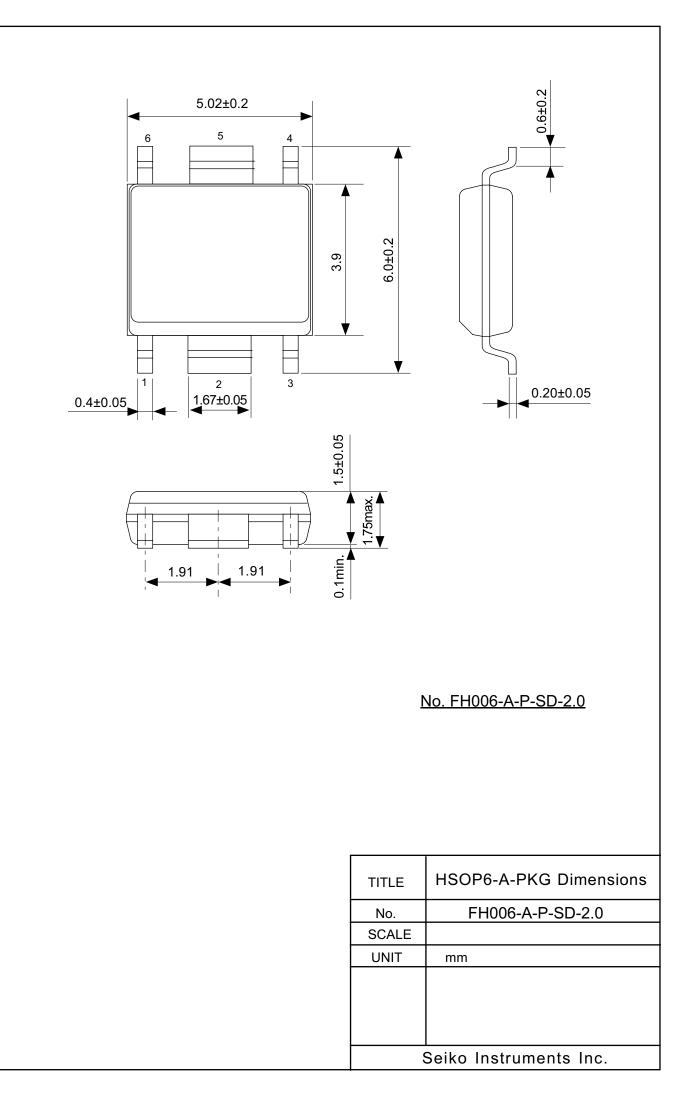


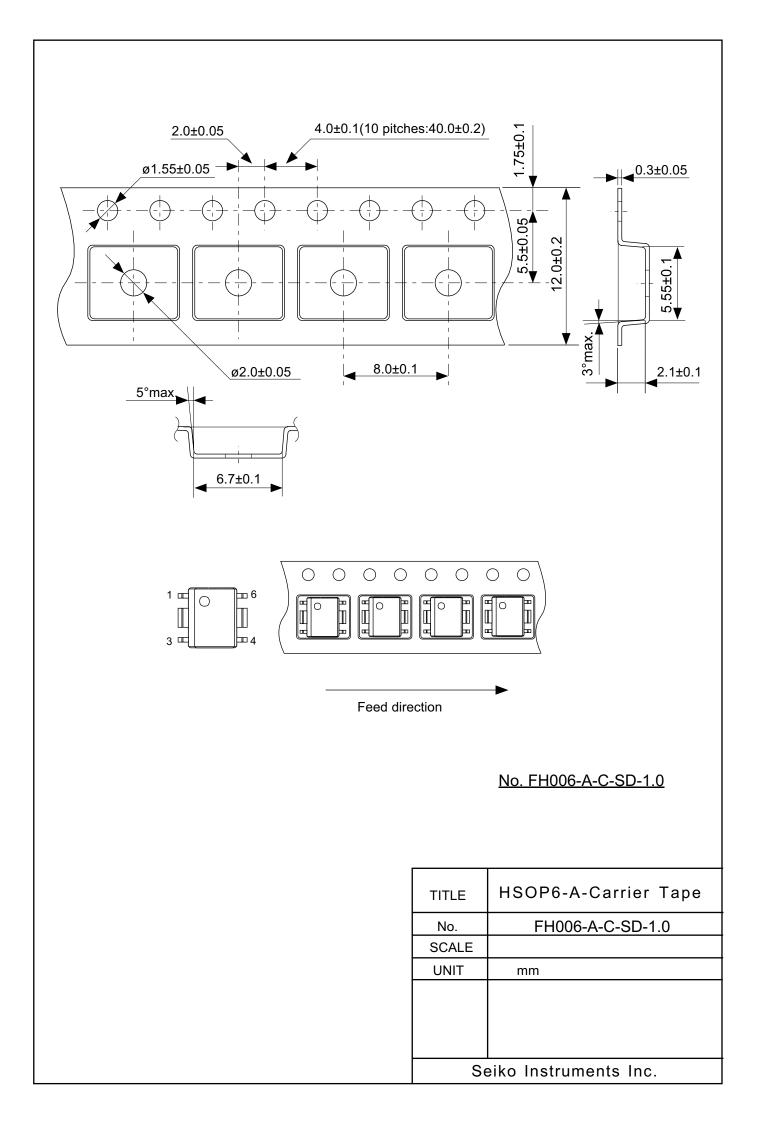
Marking Specification

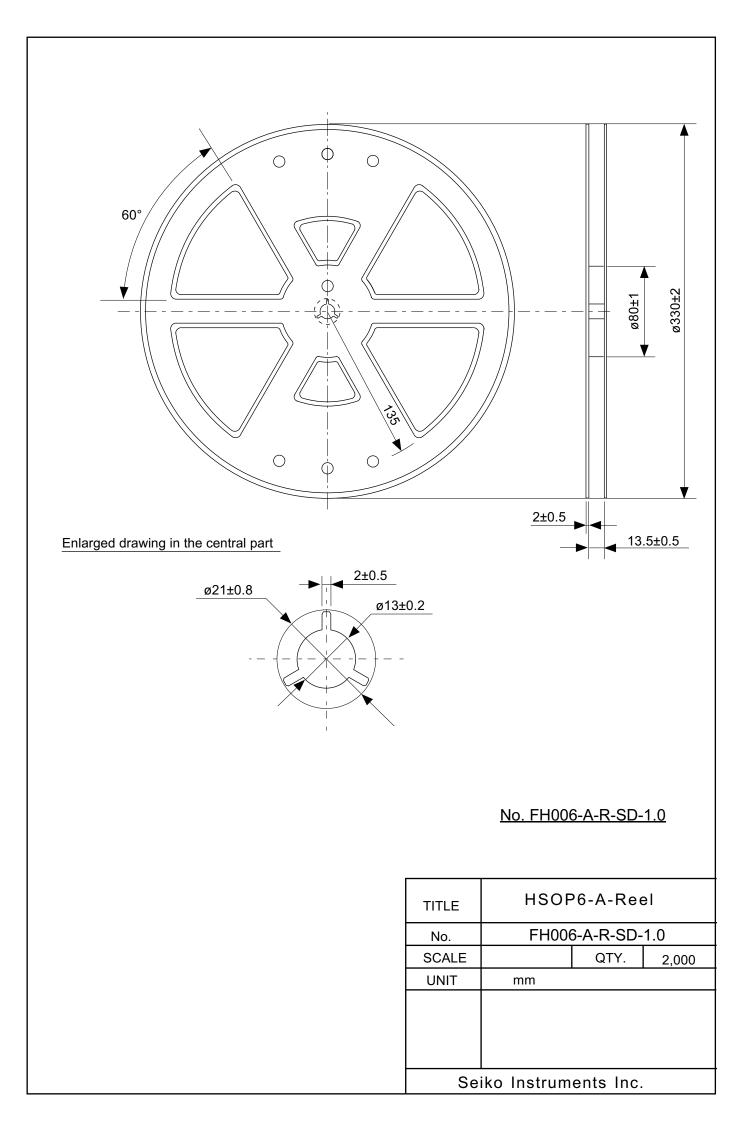
1. HSOP-6

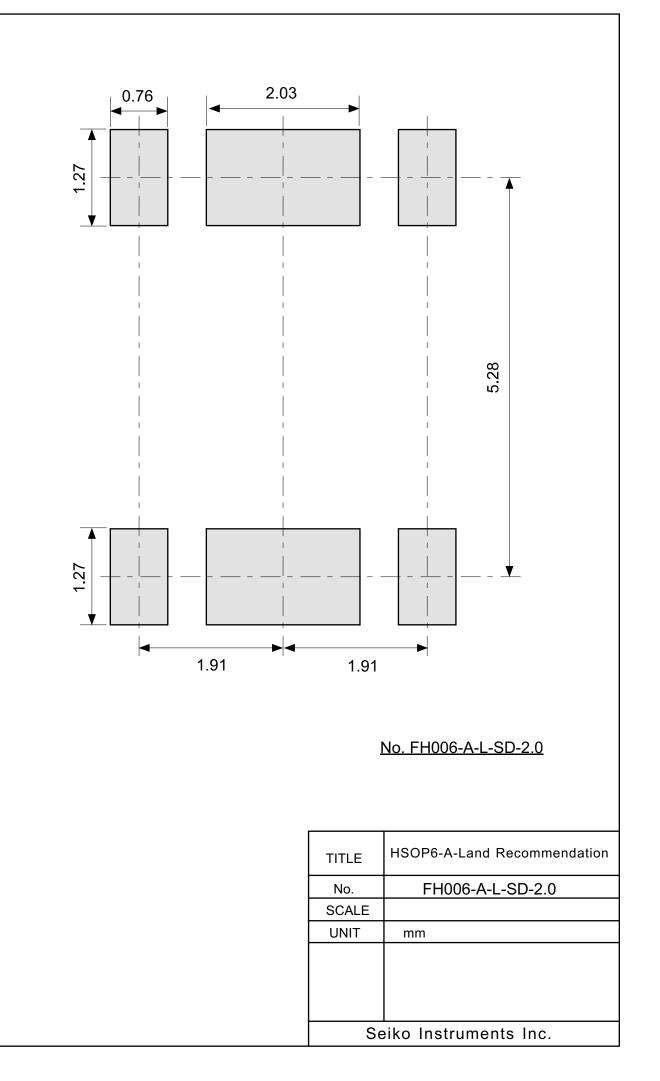


(1) to (5):	Product name: S1142 (Fixed)
(6):	Product type
(7), (8):	Value of output voltage
(9):	Operation temperature
(10) to (16):	Lot number











- The information described herein is subject to change without notice.
- Seiko Instruments Inc. is not responsible for any problems caused by circuits or diagrams described herein whose related industrial properties, patents, or other rights belong to third parties. The application circuit examples explain typical applications of the products, and do not guarantee the success of any specific mass-production design.
- When the products described herein are regulated products subject to the Wassenaar Arrangement or other agreements, they may not be exported without authorization from the appropriate governmental authority.
- Use of the information described herein for other purposes and/or reproduction or copying without the express permission of Seiko Instruments Inc. is strictly prohibited.
- The products described herein cannot be used as part of any device or equipment affecting the human body, such as exercise equipment, medical equipment, security systems, gas equipment, vehicle equipment, in-vehicle equipment, aviation equipment, aerospace equipment, and nuclear-related equipment, without prior written permission of Seiko Instruments Inc.
- The products described herein are not designed to be radiation-proof.
- Although Seiko Instruments Inc. exerts the greatest possible effort to ensure high quality and reliability, the failure or malfunction of semiconductor products may occur. The user of these products should therefore give thorough consideration to safety design, including redundancy, fire-prevention measures, and malfunction prevention, to prevent any accidents, fires, or community damage that may ensue.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ABLIC:

<u>S-1142A33I-E6T1U</u> <u>S-1142A25I-E6T1U</u> <u>S-1142A35I-E6T1U</u> <u>S-1142A20I-E6T1U</u> <u>S-1142A50I-E6T1U</u> <u>S-1142A37I-E6T1U</u> <u>S-1142A30I-E6T1U</u> <u>S-1142A30I-E6T1U</u> <u>S-1142A28I-E6T1U</u> <u>S-1142A80I-E6T1U</u> <u>S-1142A28I-E6T1U</u> <u>S-1142A28I-E6T1U</u> <u>S-1142A28I-E6T1U</u> <u>S-1142A80I-E6T1U</u> <u>S-1142A80I-E6T1U</u> <u>S-1142A28I-E6T1U</u> <u>S-1142A80I-E6T1U</u> <u>S-1142A80I-E</u>